L Number	Hits	Search Text	DB	Time stamp
1	66081	finfet fin	USPAT; US-PGPUB	2004/07/14 12:14
2	120	(finfet fin) and (crystal near3 plane)	USPAT; US-PGPUB	2004/07/14 12:15
4	64192	finfet fin	EPO; JPO; DERWENT; IBM_TDB	2004/07/14 12:14
5	4	(finfet fin) and (crystal near3 plane)	EPO; JPO; DERWENT; IBM_TDB	2004/07/14 12:14
6	64638	(SOI (silicon near5 insulat$3))	USPAT; US-PGPUB	2004/07/14 12:27
7	1708	((SOI (silicon near5 insulat$3))) and (crystal near3 plane)	USPAT; US-PGPUB	2004/07/14 12:27
8	1067	(((SOI (silicon near5 insulat$3))) and (crystal near3 plane)) and gate	USPAT; US-PGPUB	2004/07/14 12:16
9	402	((((SOI (silicon near5 insulat$3))) and (crystal near3 plane)) and gate) and (CMOS (complementary near5 metal near5 oxide))	USPAT; US-PGPUB	2004/07/14 12:17
10	183	(((((SOI (silicon near5 insulat$3))) and (crystal near3 plane)) and gate) and (CMOS (complementary near5 metal near5 oxide))) and (FET (field near5 effect near5 transistor))	USPAT; US-PGPUB	2004/07/14 12:18
11	34325	(SOI (silicon near5 insulat$3))	EPO; JPO; DERWENT; IBM_TDB	2004/07/14 12:27
12	53	((SOI (silicon near5 insulat$3))) and (crystal near3 plane)	EPO; JPO; DERWENT; IBM_TDB	2004/07/14 12:28